

# CGS74CT2524 1 to 4 Minimum Skew (300 ps) Clock Driver

### **General Description**

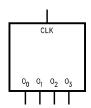
These minimum skew clock drivers are designed for Clock Generation and Support (CGS) applications operating at high frequencies. This device guarantees minimum output skew across the outputs of a given device.

Skew parameters are also provided as a means to measure duty cycle requirements as those found in high speed clocking systems. The CGS74CT2524 is a minimum skew clock driver with one input driving four outputs, specifically designed for signal generation and clock distribution applications.

### **Features**

- Guaranteed 300 ps pin-to-pin skew (t<sub>OSHL</sub> and t<sub>OSLH</sub>)
- Implemented on National's FACT™ family process
- 1 input to 4 outputs low skew clock distribution
- Symmetric output current drive: 24 mA I<sub>OH</sub>/I<sub>OL</sub>
- Industrial temperature of −40°C to +85°C
- 8-pin SOIC package
- Low dynamic power consumption above 20 MHz
- Guaranteed 2 kV ESD protection

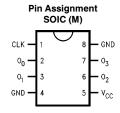
# **Logic Symbol**



TL/F/11752-1

The output pins act as a single entity and will follow the state of the CLK when the clock distribution chip is selected.

# **Connection Diagrams**



TL/F/11752-2

## **Pin Description**

Pin Names	Descripton
CLK	Clock Input
O <sub>0</sub> -O <sub>3</sub>	Outputs

### **Truth Table**

Inputs	Outputs
CLK	O <sub>0</sub> -O <sub>3</sub>
L	L
Н	Н

L = Low Logic Level H = High Logic Level CLK 0<sub>1</sub> 0<sub>2</sub> 0<sub>3</sub> TL/F/11752-3

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### **Absolute Maximum Ratings (Note)**

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

 $\label{eq:supply Voltage (VCC)} Supply Voltage (VCC) & -0.5 to 7.0 V \\ DC Input Voltage Diode Current (I_{IK}) & -20 mA \\ V = V_{CC} + 0.5 V & +20 mA \\ DC Input Voltage (V_I) & -0.5 V to (V_{CC} + 0.5 V) \\ DC Output Diode (Current) (I_O) & -0.5 V to (V_{CC} + 0.5 V) \\ DC Output Diode (Current) (I_O) & -0.5 V to (V_{CC} + 0.5 V) \\ DC Output Diode (Current) (I_O) & -0.5 V to (V_{CC} + 0.5 V) \\ DC Output Diode (Current) (I_{CC} + 0.5 V) & -0.5 V to (V_{CC} + 0.5 V) \\ DC Output Diode (Current) (I_{CC} + 0.5 V) & -0.5 V to (V_{CC} + 0.5 V) \\ DC Output Diode (Current) (I_{CC} + 0.5 V) & -0.5 V to (V_{CC} + 0.5 V) \\ DC Output Diode (Current) (I_{CC} + 0.5 V) & -0.5 V to (V_{CC} + 0.5 V) \\ DC Output Diode (Current) (I_{CC} + 0.5 V) & -0.5 V to (V_{CC} + 0.5 V) \\ DC Output Diode (Current) (I_{CC} + 0.5 V) & -0.5 V to (V_{CC} + 0.5 V) \\ DC Output Diode (Current) (I_{CC} + 0.5 V) & -0.5 V to (V_{CC} + 0.5 V) \\ DC Output Diode (Current) (I_{CC} + 0.5 V) & -0.5 V to (V_{CC} + 0.5 V) \\ DC Output Diode (Current) (I_{CC} + 0.5 V) & -0.5 V to (V_{CC} + 0.5 V) \\ DC Output Diode (Current) (I_{CC} + 0.5 V) & -0.5 V to (V_{CC} + 0.5 V) \\ DC Output Diode (Current) (I_{CC} + 0.5 V) & -0.5 V to (V_{CC} + 0.5 V) \\ DC Output Diode (Current) (I_{CC} + 0.5 V) & -0.5 V to (V_{CC} + 0.5 V) \\ DC Output Diode (Current) (I_{CC} + 0.5 V) & -0.5 V to (V_{CC} + 0.5 V) \\ DC Output Diode (Current) (I_{CC} + 0.5 V) & -0.5 V to (V_{CC} + 0.5 V) \\ DC Output Diode (Current) (I_{CC} + 0.5 V) & -0.5 V to (V_{CC} + 0.5 V) \\ DC Output Diode (Current) (I_{CC} + 0.5 V) & -0.5 V to (V_{CC} + 0.5 V) \\ DC Output Diode (Current) (I_{CC} + 0.5 V) & -0.5 V to (V_{CC} + 0.5 V) \\ DC Output Diode (Current) (I_{CC} + 0.5 V) & -0.5 V to (V_{CC} + 0.5 V) \\ DC Output Diode (Current) (I_{CC} + 0.5 V) & -0.5 V to (V_{CC} + 0.5 V) \\ DC Output Diode (Current) (I_{CC} + 0.5 V) & -0.5 V to (V_{CC} + 0.5 V) \\ DC Output Diode (Current) (I_{CC} + 0.5 V) & -0.5 V to (V_{CC} + 0.5 V) \\ DC Output Diode (Current) (I_{CC} + 0.5 V) & -0.5 V to (V_{CC} + 0.5 V) \\ DC Output Diode (Curr$ 

DC Output Source

or Sink Current (I<sub>O</sub>)  $\pm$  50 mA

DC V<sub>CC</sub> or Ground Current per Output Pin (I<sub>CC</sub> or I<sub>GND</sub>)  $\pm 50 \text{ mA}$ Storage Temperature (T<sub>STG</sub>)  $-65^{\circ}\text{C}$  to  $+150^{\circ}\text{C}$ Junction Temperature ( $\theta_{\text{JA}}$ ) 0 225 500 LFM

M 167 132 117°C/W N 115 79 62°C/W

# **Recommended Operating Conditions**

Supply Voltage ( $V_{CC}$ ) 4.5V to 5.5V Input Voltage ( $V_I$ ) 0V to  $V_{CC}$  Output Voltage ( $V_O$ ) 0 to  $V_{CC}$  Operating Temperature ( $V_A$ ) -40°C to +85°C Input Rise and Fall Times

(0.8V to 2.0V) 9.6 ns max

NOTE: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the DC and AC Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The Recommended Operating Conditions will define the conditions for actual device operation.

### **DC Electrical Characteristics**

Over recommended operating conditions unless specified otherwise.

	Parameter		CGS74CT2524			Units	
Symbol		V <sub>CC</sub> (V)	$T_A = +25^{\circ}C$ $T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		Conditions		
		(•)	Тур	Typ Guaranteed Limits			
V <sub>IH</sub>	Minimum High Level Input Voltage	4.5 5.5	1.5 1.5	2.0 2.0	2.0 2.0	V	$V_{OUT} = 0.1V$ or $V_{CC} = -0.1V$
V <sub>IL</sub>	Maximum Low Level Input Voltage	4.5 5.5	1.5 1.5	0.8 0.8	0.8 0.8	V	$V_{OUT} = 0.1V$ or $V_{CC} = -0.1V$
V <sub>OH</sub>	Minimum High Level Output Voltage	4.5 5.5	4.49 5.49	4.4 5.4	4.4 5.4	V	$V_{IN} = V_{IH}$ $I_{OUT} = -50 \mu A$
		4.5 5.5		3.86 4.86	3.76 4.76	٧	$V_{IN} = V_{IH}$ $I_{OH} = -24 \text{ mA}$
$V_{OL}$	Minimum Low Level Output Voltage	4.5 5.5	0.001 0.001	0.1 0.1	0.1 0.1	V	$V_{IN} = V_{IL}$ $I_{OUT} = 50 \mu A$
		4.5 5.5		0.36 0.36	0.44 0.44	V	$V_{IN} = V_{IL}$ $I_{OL} = 24 \text{ mA}$
I <sub>IN</sub>	Maximum Input Leakage Current	5.5		±0.1	±1.0	mA	$V_{I} = V_{CC}$ , GND
I <sub>CCT</sub>	Maximum I <sub>CC</sub> /Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$
I <sub>OLD</sub>	Minimum Dynamic	5.5			75	mA	V <sub>OLD</sub> = 1.65V Max
I <sub>OHD</sub>	Output Current	5.5			<b>−75</b>	mA	V <sub>OHD</sub> = 3.85V Min
Icc	Maximum Quiescent Supply Current	5.5		8.0	80	μΑ	$V_{IN} = V_{CC}$ or GND

### **AC Electrical Characteristics**

Over recommended operating conditions unless specified otherwise. All typical values are measured at  $V_{\rm CC}=5V$ ,  $T_{\rm A}=25^{\circ}{\rm C}$ .

Symbol	Parameter	\ T <sub>A</sub>	Units		
		Min	Тур	Max	
t <sub>PLH</sub>	Low-to-High Propagation Delay CLK to O <sub>n</sub>	3.5		9.0	ns
t <sub>PHL</sub>	High-to-Low Propagation Delay CLK to O <sub>n</sub>	3.5		9.0	ns

### **Extended AC Electrical Characteristics**

Over recommended operating conditions unless specified otherwise. All typical values are measured at  $V_{CC}=5V$ ,  $T_A=25^{\circ}C$ .

Symbol	Parameter		Units			
		т,				
		Package	Min	Тур	Max	
F <sub>max</sub>	Maximum Operating Frequency			100		MHz
t <sub>OSHL</sub>	Maximum Skew Common Edge Output-to-Output Variation (Note 1)	M M (Note 2) N			300 450 500	ps
t <sub>OSLH</sub>	Maximum Skew Common Edge Output-to-Output Variation (Note 1)	M M (Note 2) N			300 450 500	ps
t <sub>PS</sub>	Maximum Skew Pin (Signal) Transition Variation (Note 3)				1.0	ns
t <sub>rise</sub> t <sub>fall</sub>	Rise Time/Fall Time (from 0.8V to 2.0V/2.0V to 0.8V)				1.5	ns
T <sub>High</sub>	Time High	4				ns
$T_{Low}$	Time Low	4				ns

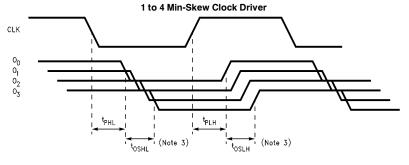
Note 1: Output-to-Output Skew is defined as the absolute value of the difference between the actual propagation delay from any outputs within the same packaged device. The specifications apply to any outputs switching in the same direction either HIGH to LOW (toshl) or LOW to HIGH (toshl) or in opposite directions both HL and LH (tosh). toshl and tosl are characterized and guaranteed by design @1 MHz.

Note 2: Characterized at 66 MHz. Parameter guaranteed by design.

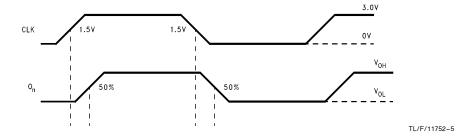
Note 3: Pin transition skew is the absolute difference between High-to-Low and Low-to-High propagation delay measure at a given output pin.

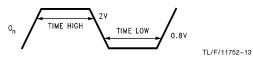
Note 4: Load capacitance includes the test jig.





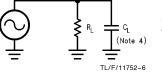
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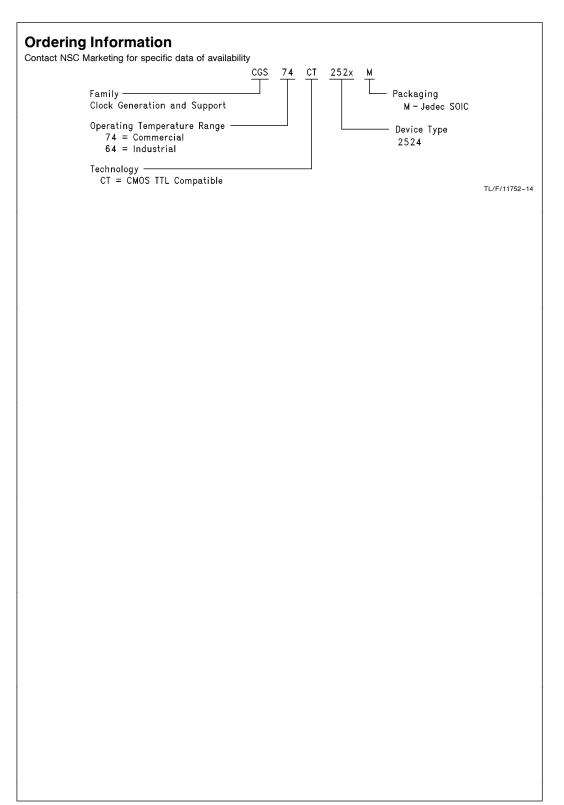


Time high is measured with outputs above 2V. Time low is measured with outputs below 0.8V.

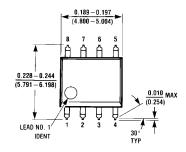
# **Test Circuit**

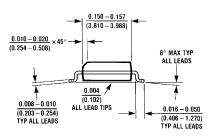


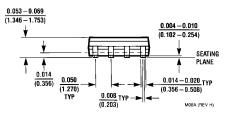
 ${\rm R_L}$  is 500  $\!\Omega$   ${\rm C_L}$  is 50 pF for all prop delays and skew measurements.



### Physical Dimensions inches (millimeters)







8 Lead (0.150" Wide) Molded Small Outline Package (M) NS Package Number M08A

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